TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LCX16240AFT

Low-Voltage 16-Bit Bus Buffer (inverted) with 5-V Tolerant Inputs and Outputs

The TC74LCX16240AFT is a high-performance CMOS 16-bit bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

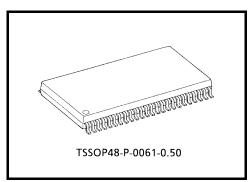
The device is designed for low-voltage  $(3.3 \text{ V}) \text{ V}_{CC}$  applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This device is inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the  $\overline{OE}$  input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

#### Features

- Low-voltage operation:  $V_{CC} = 2.0$  to 3.6 V
- High-speed operation:  $t_{pd} = 4.9 \text{ ns} (max) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current:  $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Package: TSSOP (thin shrink small outline package)
- Power-down protection provided on all inputs and outputs



Weight: 0.25 g (typ.)

## Pin Assignment (top view)

			1	
10E	1	$\bigcirc$	48	20E
1¥1	2		47	1A1
1¥2	3		46	1A2
GND	4		45	GND
1 <del>7</del> 3	5		44	1A3
$1\overline{Y}4$	6		43	1A4
V <sub>CC</sub>	7		42	V <sub>CC</sub>
2¥1	8		41	2A1
2¥2	9		40	2A2
GND	10		39	GND
2¥3	11		38	2A3
2¥4	12		37	2A4
3 <del>\</del> 1	13		36	3A1
3 <del>7</del> 2	14		35	3A2
GND	15		34	GND
3 <del>7</del> 3	16		33	3A3
3 <del>7</del> 4	17		32	3A4
V <sub>CC</sub>	18		31	V <sub>CC</sub>
$4\overline{Y}1$	19		30	4A1
$4\overline{Y}2$	20		29	4A2
GND	21		28	GND
4 <del>7</del> 3	22		27	4A3
$4\overline{Y}4$	23		26	4A4
40E	24		25	30E
			1	

## IEC Logic Symbol

$\begin{array}{c c c c c c c c c c c c c c c c c c c $								
1A1       1 $1 $ $1 $ $1 $ 1A2       46       3 $1$ $1$ 1A3       44       5 $1$ $1$ 1A3       44       5 $1$ $1$ 1A4       43       6 $1$ $1$ 2A1       41       1 $2$ $8$ $2$ 2A3       38       11 $2$ $9$ $2$ 2A3       38       11 $2$ $2$ $2$ 2A3       38       11 $2$ $2$ $2$ 2A4       37       12 $2$ $2$ $3$ 3A1       36       1 $3$ $13$ $3$ 3A2       35       14 $3$ $3$ $3$ 3A4       32       17 $3$ $3$ 4A1       30       1 $4$ $4$ 4A3       27       22 $4$ $4$	2 <del>0E</del> — 3 <del>0E</del> —	48	EN2 EN3					
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	1A2 —	46		1	17	\\	3	1 <u>7</u> 2
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	1A4 —			1	2▽	>	6	1 <u>¥</u> 4
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	2A2 —	38		•	- •	<u> </u>	11	2 <u>7</u> 2
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		36		1	3▽	>	13	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		33				>	16	3 <u>7</u> 3
$\begin{array}{c} 4A2 \\ 4A3 \\ \hline 27 \\ 4A3 \\ \hline 22 \\ 4\overline{Y3} \end{array} $	4A1-	30		1	4▽	>	19	4 <u>7</u> 1
	4A3 —	27				<u> </u>	22	4 <u>7</u> 3

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#### **Truth Table**

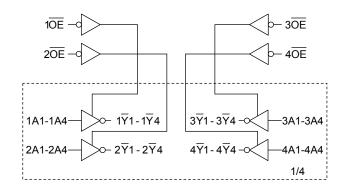
Inp	Outputs	
10E 1A1-1A4		$1\overline{Y}1 - 1\overline{Y}4$
L	L	Н
L	Н	L
Н	Х	Z

Inp	Outputs	
20E 2A1-2A4		$2\overline{Y}1 - 2\overline{Y}4$
L	L	Н
L	н	L
Н	Х	Z

Inp	Outputs	
30E 3A1-3A4		3 <del>7</del> 1-3 <del>7</del> 4
L	L	Н
L	Н	L
Н	Х	Z

Inp	Outputs						
40E	$4\overline{Y}1-4\overline{Y}4$						
L	L	Н					
L	Н	L					
Н	Х	Z					

#### System Diagram



X: Don't care

Z: High impedance

#### Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	–0.5 to 7.0	V
Input voltage	V <sub>IN</sub>	–0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
Output voltage	V <sub>OUT</sub>	–0.5 to V <sub>CC</sub> + 0.5	V
		(Note 3)	
Input diode current	I <sub>IK</sub>	-50	mA
Output diode current	IOK	±50 (Note 4)	mA
DC output current	IOUT	±50	mA
Power dissipation	PD	400	mW
DC V <sub>CC</sub> /ground current per supply pin	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND, V_{OUT} > V_{CC}$ 

#### **Recommended Operating Conditions (Note 1)**

Characteristics	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	2.0 to 3.6	V
Power suppry voltage	VCC	1.5 to 3.6 (Note 2)	v
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	0 to 5.5 (Note 3)	V	
Oulput voltage	VOUT	0 to $V_{CC}$ (Note 4)	v
Output current	leu/leu	±24 (Note 5)	mA
Output current	IOH/IOL	±12 (Note 6)	ША
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V

Note 1: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5:  $V_{CC} = 3.0$  to 3.6 V

Note 6:  $V_{CC} = 2.7$  to 3.0 V

Note 7:  $V_{IN}=0.8$  to 2.0 V,  $V_{CC}=3.0$  V

#### **Electrical Characteristics**

#### DC Characteristics (Ta = -40 to 85°C)

Characte	riation	Symbol	Test	Condition		Min	Max	Unit
Characte	IISUCS	Symbol	Test	Condition	V <sub>CC</sub> (V)	IVIITI	Max  0.8  0.2 0.4 0.4 0.55 ±5.0 ±5.0 10.0 20.0 +20.0	Unit
Input voltage	H-level	VIH		—	2.7 to 3.6	2.0		v
input voltage	L-level	VIL		_	2.7 to 3.6	_	$\begin{array}{c ccccc} .0 & & \\ - & 0.8 \\ \hline \\ .2 & \\ .2 & \\ .2 & \\ .4 & \\ .2 & \\ .2 & \\ 0.2 \\ & 0.2 \\ & 0.4 \\ & 0.4 \\ & 0.55 \\ & \pm 5.0 \\ & \pm 5.0 \\ & \pm 5.0 \\ & \pm 5.0 \\ & \pm 20.0 \\ & \pm 20.0 \\ & \pm 20.0 \\ & \pm 20.0 \end{array}$	v
				I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> -0.2	_	
	H-level	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				I <sub>OH</sub> = -18 mA	3.0	2.4	_	
Output voltage				I <sub>OH</sub> = -24 mA	3.0	2.2		
			$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 100 \ \mu A$	2.7 to 3.6	_	0.2	
	L-level	Voi		$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
	L-level	VOL		$I_{OL} = 16 \text{ mA}$	3.0	_	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55	
Input leakage curre	nt	l <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μA
3-state output OFF state current		I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±5.0	μΑ
Power-off leakage current		IOFF	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V	$V_{IN}/V_{OUT} = 5.5 V$		_	10.0	μA
			V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6	_	20.0	
Quiescent supply c	urrent	ICC	V <sub>IN</sub> /V <sub>OUT</sub> = 3.6 to 5.5 V		2.7 to 3.6	_	±20.0	μA
Increase in Icc per	input	Δl <sub>CC</sub>	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		500	

AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	2.7		5.9	ns
	t <sub>pHL</sub>		$\textbf{3.3}\pm\textbf{0.3}$	1.5	4.9	
3-state output enable time	t <sub>pZL</sub>	Figure 1, Figure 3	2.7	_	7.5	ns
	t <sub>pZH</sub>		$\textbf{3.3}\pm\textbf{0.3}$	1.5	6.5	
2 state output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3	2.7	_	6.5	ns
3-state output disable time	t <sub>pHZ</sub>		$\textbf{3.3}\pm\textbf{0.3}$	1.5	5.5	115
	t <sub>osLH</sub>	(Note)	2.7		_	20
Output to output skew	t <sub>osHL</sub>	(NOLE)	$\textbf{3.3}\pm\textbf{0.3}$	_	1.0	ns

Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$ 

## Dynamic Switching Characteristics

#### (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	$V_{IH} = 3.3 V, V_{IL} = 0 V$	3.3	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

#### **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>	_	3.3	7	pF
Output capacitance	COUT		3.3	8	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (No	e) 3.3	25	pF

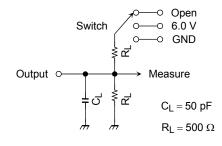
Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16$  (per bit)

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#### **AC Test Circuit**



Parameter	Switch
t <sub>pLH</sub> , t <sub>pHL</sub>	Open
t <sub>pLZ</sub> , t <sub>pZL</sub>	6.0 V
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND



#### AC Waveform

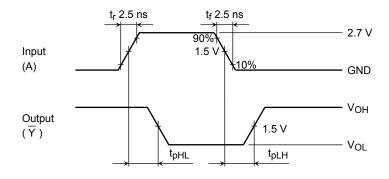


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

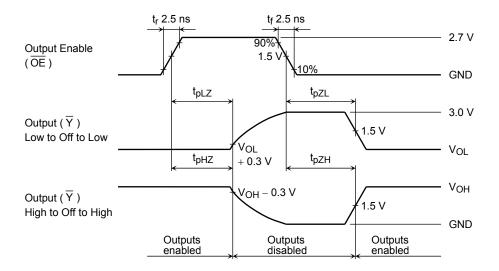
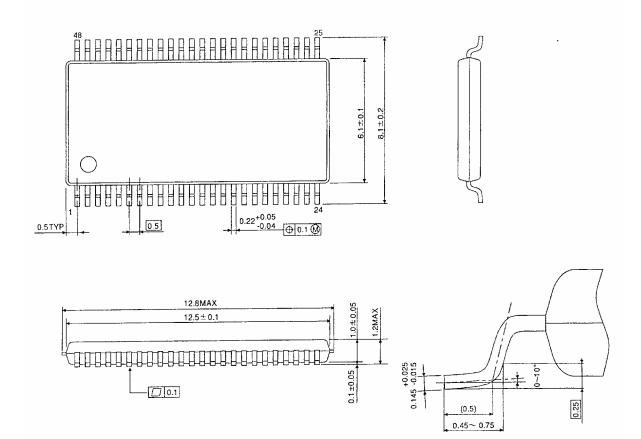


Figure 3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$ 

#### **Package Dimensions**

TSSOP48-P-0061-0.50

Unit : mm



Weight: 0.25 g (typ.)

Note: Lead (Pb)-Free Packages TSSOP48-P-0061-0.50

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